TITLE: ATOMIC LÄYER-DEPOSITED LAALO3 FILMS FOR GATE DIELETRICS INVENTORS NAME: Kie Y. Ahn et al.
DOCKET NO.: 1303.050US2

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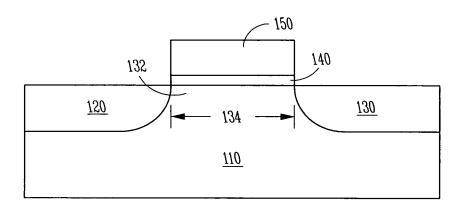


Fig.1

TITLE: ATOMIC LAYER-DEPOSITED LAALO3 FILMS FOR GATE DIELETRICS

INVENTORS NAME: Kie Y. Ahn et al. DOCKET NO.: 1303.050US2

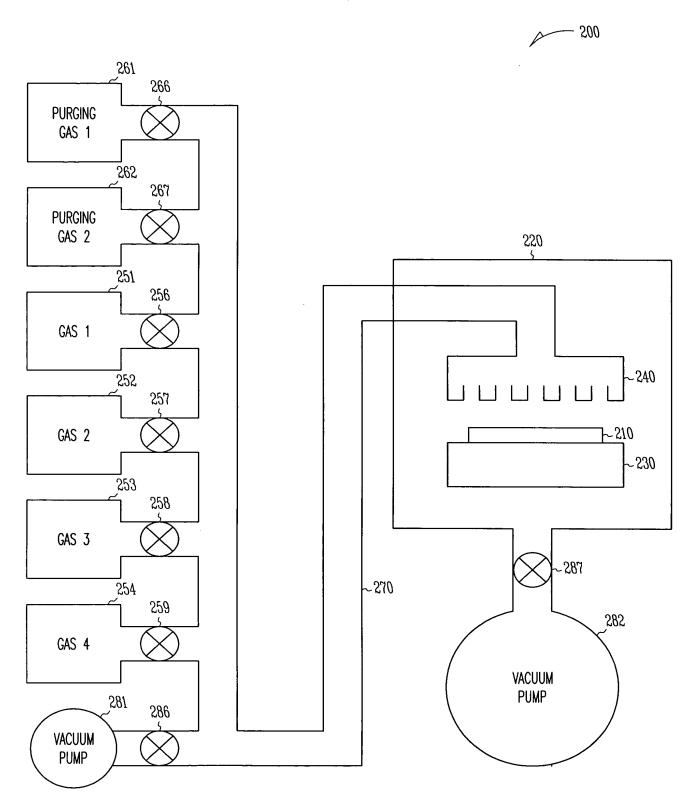


Fig.2A

TITLE: ATOMIC LAYER-DEPOSITED LAALO3 FILMS FOR GATE DIELETRICS INVENTORS NAME: Kie Y. Ahn et al. DOCKET NO.: 1303.050US2

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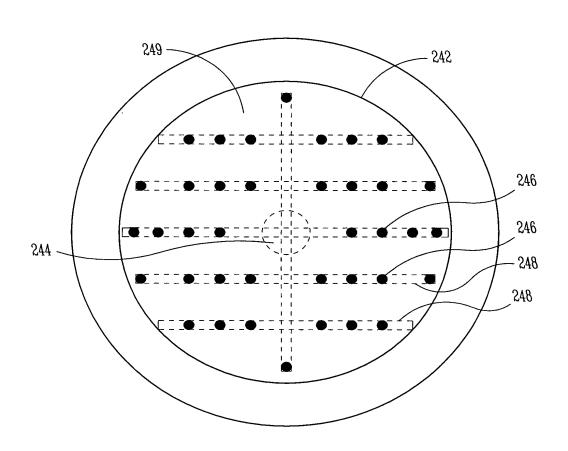


Fig.2B

TITLE: ATOMIC LAYER-DEPOSITED LAALO3 FILMS FOR GATE DIELETRICS

INVENTORS NAME: Kie Y. Ahn et al. DOCKET NO.: 1303.050US2

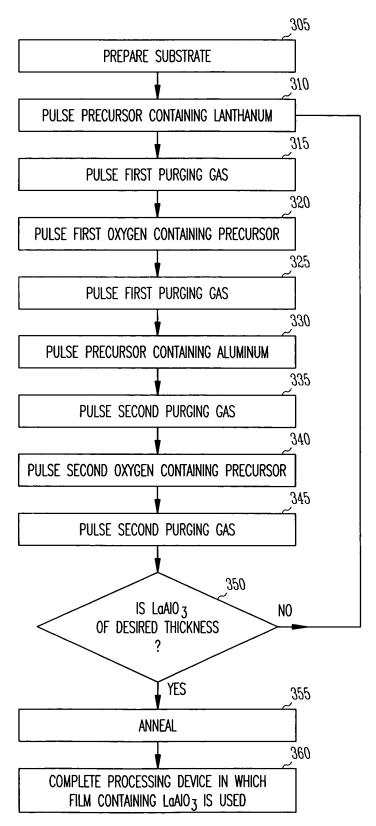


Fig.3

TITLE: ATOMIC LÂYER-DEPOSITED LAALO3 FILMS FOR GATE DIELETRICS INVENTORS NAME: Kie Y. Ahn et al. DOCKET NO.: 1303.050US2

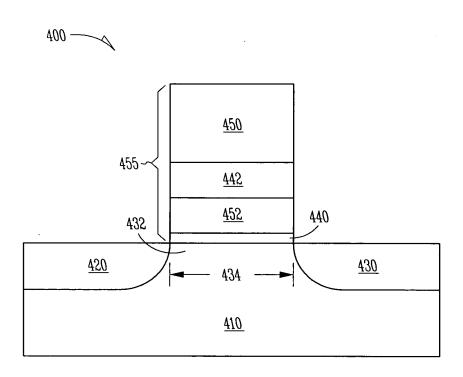
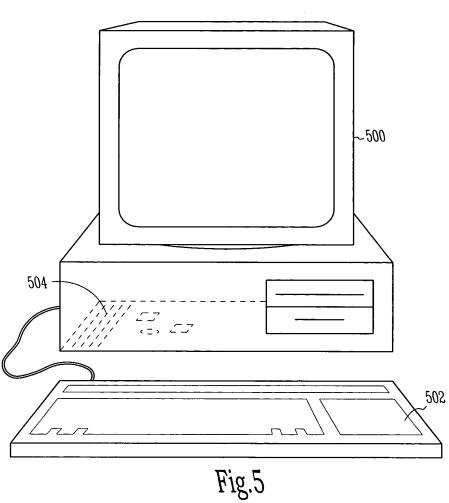
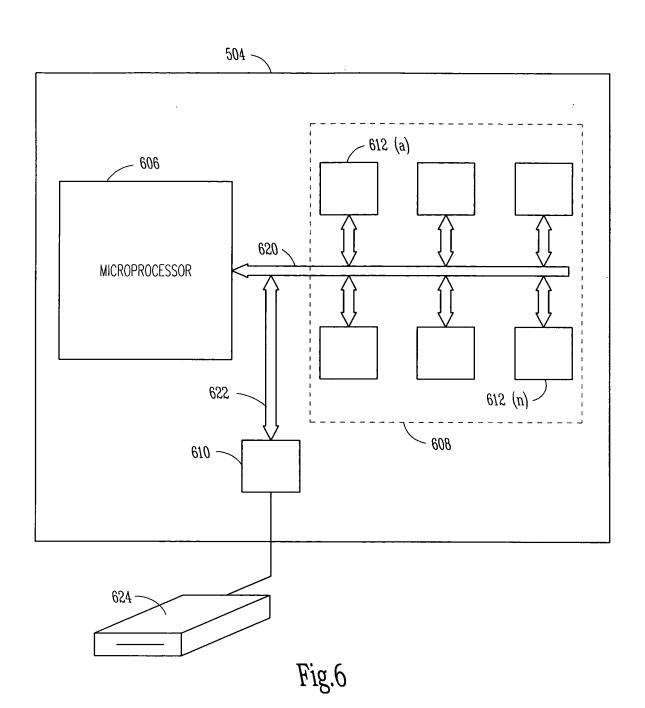


Fig.4

TITLE: ATOMIC LAYER-DEPOSITED LAALO3 FILMS FOR GATE DIELETRICS INVENTORS NAME: Kie Y. Ahn et al. DOCKET NO.: 1303.050US2



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